

LP3882 1.5A Fast-Response Ultra Low Dropout Linear Regulators

Check for Samples: LP3882

FEATURES

- Ultra Low Dropout Voltage (110 mV at 1.5A typ)
- Low Ground Pin Current
- Load Regulation of 0.04%/A
- 60 nA Typical Quiescent Current in Shutdown
- 1.5% Output Accuracy (25°C)
- TO-220, DDPAK/TO-263 and SO PowerPad Packages
- Over Temperature/Over Current Protection
- -40°C to +125°C Junction Temperature Range

APPLICATIONS

- DSP Power Supplies
- Server Core and I/O Supplies
- PC Add-in-Cards
- Local Regulators in Set-Top Boxes
- Microcontroller Power Supplies
- High Efficiency Power Supplies
- SMPS Post-Regulators

DESCRIPTION

The LP3882 is a high current, fast response regulator which can maintain output voltage regulation with minimum input to output voltage drop. Fabricated on a CMOS process, the device operates from two input voltages: Vbias provides voltage to drive the gate of the N-MOS power transistor, while Vin is the input voltage which supplies power to the load. The use of an external bias rail allows the part to operate from ultra low Vin voltages. Unlike bipolar regulators, the CMOS architecture consumes extremely low quiescent current at any output load current. The use of an N-MOS power transistor results in wide bandwidth, yet minimum external capacitance is required to maintain loop stability.

The fast transient response of these devices makes them suitable for use in powering DSP, Microcontroller Core voltages and Switch Mode Power Supply post regulators. The parts are available in TO-220, DDPAK/TO-263 and SO PowerPad packages.

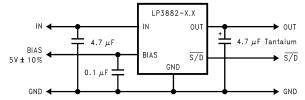
Dropout Voltage: 110 mV (typ) at 1.5A load current.

Ground Pin Current: 3 mA (typ) at full load.

Shutdown Current: 60 nA (typ) when S/D pin is low. Precision Output Voltage: 1.5% room temperature

accuracy.

TYPICAL APPLICATION CIRCUIT



At least 4.7 µF of input and output capacitance is required for stability.

AVA.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

CONNECTION DIAGRAM

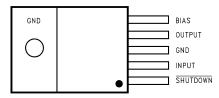


Figure 1. 5-Pin TO-220, Top View See NDH0005D Package

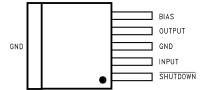


Figure 2. 5-Pin DDPAK/TO-263, Top View See KTT0005B Package

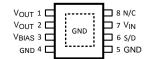
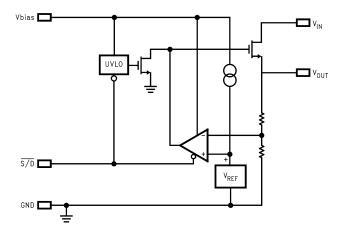


Figure 3. 8-Pin SO PowerPad, Top View See DDA0008D Package

BLOCK DIAGRAM





ABSOLUTE MAXIMUM RATINGS (1)

If Military/Aerospace specified devices are required, contact the Texas Instruments Semiconductor Sales Office/ Distributors for availability and specifications.

		VALUE / UNITS
Storage Temp	perature Range	−65°C to +150°C
Lead Temper	ature (Soldering, 5 seconds)	260°C
LOD Italing	Human Body Model (2)	2 kV
	Machine Model (3)	200V
Power Dissipa	ation ⁽⁴⁾	Internally Limited
V _{IN} Supply Vo	oltage (Survival)	-0.3V to +6V
V _{BIAS} Supply	Voltage (Survival)	-0.3V to +7V
Shutdown Inp	out Voltage (Survival)	-0.3V to +7V
I _{OUT} (Survival)	Internally Limited
Output Voltag	e (Survival) ⁽⁵⁾	-0.3V to +6V
Junction Tem	perature	-40°C to +150°C

- (1) Absolute maximum ratings indicate limits beyond which damage to the component may occur. Operating ratings indicate conditions for which the device is intended to be functional, but does **not** ensure specific performance limits. For specifications, see Electrical Characteristics. Specifications do not apply when operating the device outside of its rated operating conditions.
- (2) The human body model is a 100 pF capacitor discharged through a 1.5k resistor into each pin.
- (3) The machine model is a 220 pF capacitor discharged directly into each pin. The machine model ESD rating of pin 5 is 100V.
- (4) At elevated temperatures, device power dissipation must be derated based on package thermal resistance and heatsink thermal values. θ_{J-A} for TO-220 devices is 65°C/W if no heatsink is used. If the TO-220 device is attached to a heatsink, a θ_{J-S} value of 4°C/W can be assumed. θ_{J-A} for DDPAK/TO-263 devices is approximately 40°C/W if soldered down to a copper plane which is at least 1.5 square inches in area. θ_{J-A} value for typical SO PowerPad PC board mounting is 166°C/W. If power dissipation causes the junction temperature to exceed specified limits, the device will go into thermal shutdown.
- (5) If used in a dual-supply system where the regulator load is returned to a negative supply, the output pin must be diode clamped to ground.

RECOMMENDED OPERATING CONDITIONS

	VALUE / UNITS
V _{IN} Supply Voltage	$(V_{OUT} + V_{DO})$ to 5.5V
Shutdown Input Voltage	0 to +6V
lout	1.5A
Operating Junction Temperature Range	-40°C to +125°C
V _{BIAS} Supply Voltage	4.5V to 6V

Product Folder Links: LP3882



ELECTRICAL CHARACTERISTICS

Limits in standard typeface are for $T_J = 25^{\circ}$ C, and limits in **boldface type** apply over the full operating temperature range. Unless otherwise specified: $V_{IN} = V_O(NOM) + 1V$, $V_{BIAS} = 4.5V$, $I_L = 10$ mA, $C_{IN} = C_{OUT} = 4.7 \mu F$, $V_{S/D} = V_{BIAS}$.

Symbol	Parameter	Conditions	MIN ⁽¹⁾	Typical (2)	MAX ⁽¹⁾	Units	
Vo	Output Voltage Tolerance	10 mA < I_L < 1.5A $V_O(NOM)$ + 1V ≤ V_{IN} ≤ 5.5V	1.198 1.186	1.216	1.234 1.246		
		$4.5V \le V_{BIAS} \le 6V$	1.478 1.455	1.5	1.522 1.545	V	
			1.773 1.746	1.8	1.827 1.854		
$\Delta V_{O}/\Delta V_{IN}$	Output Voltage Line Regulation (3)	$V_O(NOM) + 1V \le V_{IN} \le 5.5V$		0.01		%/V	
$\Delta V_{O}/\Delta I_{L}$	Output Voltage Load Regulation (4)	10 mA < I _L < 1.5A		0.04 0.06		%/A	
V_{DO}	Dropout Voltage (5)	I _L = 1.5A (TO-220 and DDPAK/TO-263 only)		110	170 270	m)/	
		I _L = 1.5A (PSOP only)		125	190 320	mV	
$I_Q(V_{IN})$	Quiescent Current Drawn from V _{IN} Supply	10 mA < I _L < 1.5A		3	7 8	mA	
		$V_{\overline{S/D}} \le 0.3V$		0.03	1 30	μΑ	
$I_Q(V_{BIAS})$	Quiescent Current Drawn from V _{BIAS} Supply	10 mA < I _L < 1.5A		1	2 3	mA	
		$V_{\overline{S/D}} \le 0.3V$		0.03	1 30	μΑ	
I _{SC}	Short-Circuit Current	V _{OUT} = 0V		4.3		Α	
Shutdown I	nput						
V _{SDT}	Output Turn-off Threshold	Output = ON	1.3	0.7		V	
		Output = OFF		0.7	0.3	v	
Td (OFF)	Turn-OFF Delay	R _{LOAD} X C _{OUT} << Td (OFF)		20			
Td (ON)	Turn-ON Delay	R _{LOAD} X C _{OUT} << Td (ON)		15		μs	
I _{S/D}	S/D Input Current	V _{S/D} =1.3V		1			
		V _{S/D} ≤ 0.3V		-1		μA	
AC Paramet	ers						
PSRR (V _{IN})	Ripple Rejection for V _{IN} Input Voltage	V _{IN} = V _{OUT} +1V, f = 120 Hz		80			
		V _{IN} = V _{OUT} + 1V, f = 1 kHz		65		.in	
PSRR	Ripple Rejection for V _{BIAS} Voltage	V _{BIAS} = V _{OUT} + 3V, f = 120 Hz		70		dB	
(V _{BIAS})		V _{BIAS} = V _{OUT} + 3V, f = 1 kHz		65]	
	Output Noise Density	f = 120 Hz		1		μV/ Hz	
e _n	Output Noise Voltage	BW = 10 Hz - 100 kHz		150		11// /200 = 1	
	$V_{OUT} = 1.8V$	BW = 300 Hz - 300 kHz		90		μV (rms)	

- Limits are specified through testing, statistical correlation, or design. Typical numbers represent the most likely parametric norm for 25°C operation.
- Output voltage line regulation is defined as the change in output voltage from nominal value resulting from a change in input voltage.
- Output voltage load regulation is defined as the change in output voltage from nominal value as the load current increases from no load to full load.
- Dropout voltage is defined as the minimum input to output differential required to maintain the output with 2% of nominal value. The SO PowerPad package devices have a slightly higher dropout voltage due to increased band wire resistance.



TYPICAL PERFORMANCE CHARACTERISTICS

Unless otherwise specified: $T_A = 25$ °C, $C_{OUT} = 4.7 \mu F$, $Cin = 4.7 \mu F$, $\overline{S/D}$ pin is tied to V_{BIAS} , $V_{IN} = 2.2 V$, $V_{OUT} = 1.8 V$.

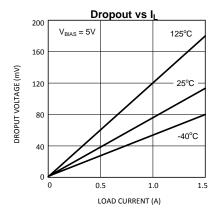
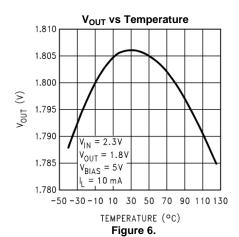
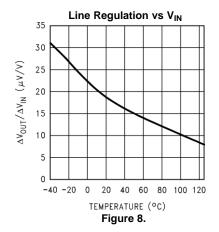


Figure 4.





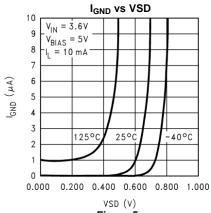


Figure 5.

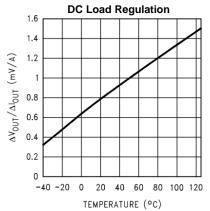
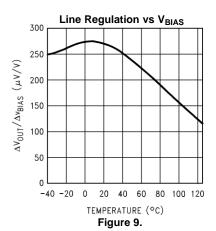


Figure 7.



Copyright © 2003–2013, Texas Instruments Incorporated



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Unless otherwise specified: $T_A = 25^{\circ}C$, $C_{OUT} = 4.7 \mu F$, $Cin = 4.7 \mu F$, $\overline{S/D}$ pin is tied to V_{BIAS} , $V_{IN} = 2.2 V$, $V_{OUT} = 1.8 V$.

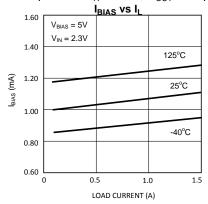


Figure 10.

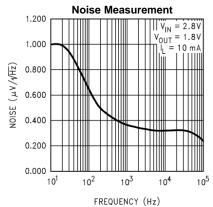
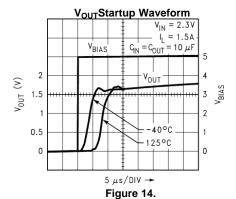


Figure 12.



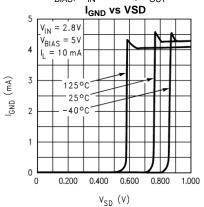


Figure 11.

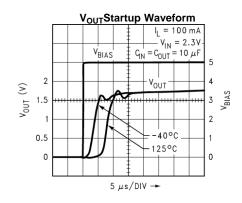
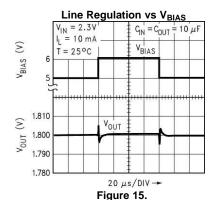


Figure 13.





TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Unless otherwise specified: $T_A = 25^{\circ}C$, $C_{OUT} = 4.7\mu F$, $Cin = 4.7\mu F$, $\overline{S/D}$ pin is tied to V_{BIAS} , $V_{IN} = 2.2V$, $V_{OUT} = 1.8V$.

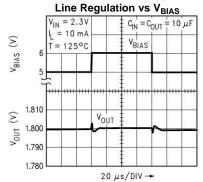
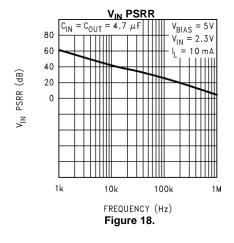


Figure 16.



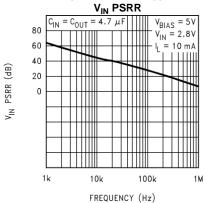


Figure 17.

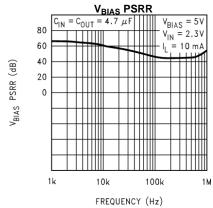


Figure 19.



Application Hints

EXTERNAL CAPACITORS

To assure regulator stability, input and output capacitors are required as shown in the Typical Application Circuit.

OUTPUT CAPACITOR

At least $4.7\mu F$ of output capacitance is required for stability (the amount of capacitance can be increased without limit). The output capacitor must be located less than 1 cm from the output pin of the IC and returned to a clean analog ground. The ESR (equivalent series resistance) of the output capacitor must be within the "stable" range as shown in the graph below over the full operating temperature range for stable operation.

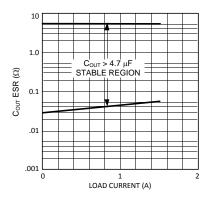


Figure 20. Minimum ESR vs Output Load Current

Tantalum capacitors are recommended for the output as their ESR is ideally suited to the part's requirements and the ESR is very stable over temperature. Aluminum electrolytics are not recommended because their ESR increases very rapidly at temperatures below 10C. Aluminum caps can only be used in applications where lower temperature operation is not required.

A second problem with Al caps is that many have ESR's which are only specified at low frequencies. The typical loop bandwidth of a linear regulator is a few hundred kHz to several MHz. If an Al cap is used for the output cap, it must be one whose ESR is specified at a frequency of 100 kHz or more.

Because the ESR of ceramic capacitors is only a few milli Ohms, they are not suitable for use as output capacitors on LP388X devices. The regulator output can tolerate ceramic capacitance totaling up to 15% of the amount of Tantalum capacitance connected from the output to ground.

OUTPUT "BYPASS" CAPACITORS

Many designers place small value "bypass" capacitors at various circuit points to reduce noise. Ceramic capacitors in the value range of about 1000pF to 0.1µF placed directly on the output of a PNP or P-FET LDO regulator can cause a loss of phase margin which can result in oscillations, even when a Tantalum output capacitor is in parallel with it. This is not unique to Texas Instruments Semiconductor LDO regulators, it is true of any P-type LDO regulator.

The reason for this is that PNP or P-FET regulators have a higher output impedance (compared to an NPN regulator), which results in a pole-zero pair being formed by every different capacitor connected to the output.

The zero frequency is approximately:

$$F_z = 1 / (2 \times \pi \times ESR \times C)$$
 (1)

Where ESR is the equivalent series resistance of the capacitor, and C is the value of capacitance.

The pole frequency is:

$$F_p = 1 / (2 \times \pi \times R_L \times C)$$
 (2)

Where R_I is the load resistance connected to the regulator output.

Product Folder Links: LP3882



To understand why a small capacitor can reduce phase margin: assume a typical LDO with a bandwidth of 1MHz, which is delivering 0.5A of current from a 2.5V output (which means R_L is 5 Ohms). We then place a .047 μF capacitor on the output. This creates a pole whose frequency is:

$$F_p = 1 / (2 \times \pi \times 5 \times .047 \times 10E-6) = 677 \text{ kHz}$$
 (3)

This pole would add close to 60 degrees of phase lag at the crossover (unity gain) frequency of 1 MHz, which would almost certainly make this regulator oscillate. Depending on the load current, output voltage, and bandwidth, there are usually values of small capacitors which can seriously reduce phase margin. If the capacitors are ceramic, they tend to oscillate more easily because they have very little internal inductance to damp it out. If bypass capacitors are used, it is best to place them near the load and use trace inductance to "decouple" them from the regulator output.

INPUT CAPACITOR

The input capacitor must be at least 4.7 μ F, but can be increased without limit. It's purpose is to provide a low source impedance for the regulator input. Ceramic capacitors work best for this, but Tantalums are also very good. There is no ESR limitation on the input capacitor (the lower, the better). Aluminum electrolytics can be used, but their ESR increase very quickly at cold temperatures. They are not recommended for any application where temperatures go below about 10° C.

BIAS CAPACITOR

The 0.1µF capacitor on the bias line can be any good quality capacitor (ceramic is recommended).

BIAS VOLTAGE

The bias voltage is an external voltage rail required to get gate drive for the N-FET pass transistor. Bias voltage must be in the range of 4.5 - 6V to assure proper operation of the part.

UNDER VOLTAGE LOCKOUT

The bias voltage is monitored by a circuit which prevents the regulator output from turning on if the bias voltage is below approximately 4V.

SHUTDOWN OPERATION

Pulling down the shutdown $\overline{(S/D)}$ pin will turn-off the regulator. Pin $\overline{S/D}$ must be actively terminated through a pull-up resistor (10 k Ω to 100 k Ω) for a proper operation. If this pin is driven from a source that actively pulls high and low (such as a CMOS rail to rail comparator), the pull-up resistor is not required. This pin must be tied to Vin if not used.

POWER DISSIPATION/HEATSINKING

A heatsink may be required depending on the maximum power dissipation and maximum ambient temperature of the application. Under all possible conditions, the junction temperature must be within the range specified under operating conditions. The total power dissipation of the device is given by:

$$P_D = (V_{IN} - V_{OUT})I_{OUT} + (V_{IN})I_{GND}$$

where I_{GND} is the operating ground current of the device.

The maximum allowable temperature rise (T_{Rmax}) depends on the maximum ambient temperature (T_{Amax}) of the application, and the maximum allowable junction temperature (T_{Amax}):

$$T_{Rmax} = T_{Jmax} - T_{Amax}$$

The maximum allowable value for junction to ambient Thermal Resistance, θ_{JA} , can be calculated using the formula:

$$\theta_{JA} = T_{Rmax} / P_{D}$$

These parts are available in TO-220 and DDPAK/TO-263 packages. The thermal resistance depends on amount of copper area or heat sink, and on air flow. If the maximum allowable value of θ_{JA} calculated above is \geq 60 °C/W for TO-220 package and \geq 60 °C/W for DDPAK/TO-263 package no heatsink is needed since the package can dissipate enough heat to satisfy these requirements. If the value for allowable θ_{JA} falls below these limits, a heat sink is required.

Copyright © 2003–2013, Texas Instruments Incorporated



HEATSINKING TO-220 PACKAGE

The thermal resistance of a TO-220 package can be reduced by attaching it to a heat sink or a copper plane on a PC board. If a copper plane is to be used, the values of θ_{JA} will be same as shown in next section for DDPAK/TO-263 package.

The heatsink to be used in the application should have a heatsink to ambient thermal resistance,

$$\theta_{HA} \le \theta_{JA} - \theta_{CH} - \theta_{JC}$$
.

In this equation, θ_{CH} is the thermal resistance from the case to the surface of the heat sink and θ_{JC} is the thermal resistance from the junction to the surface of the case. θ_{JC} is about 3°C/W for a TO-220 package. The value for θ_{CH} depends on method of attachment, insulator, etc. θ_{CH} varies between 1.5°C/W to 2.5°C/W. If the exact value is unknown, 2°C/W can be assumed.

HEATSINKING DDPAK/TO-263 PACKAGE

The DDPAK/TO-263 package uses the copper plane on the PCB as a heatsink. The tab of these packages are soldered to the copper plane for heat sinking. The graph below shows a curve for the θ_{JA} of DDPAK/TO-263 package for different copper area sizes, using a typical PCB with 1 ounce copper and no solder mask over the copper area for heat sinking.

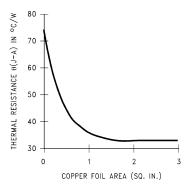


Figure 21. θ_{JA} vs Copper (1 Ounce) Area for DDPAK/TO-263 package

As shown in the graph below, increasing the copper area beyond 1 square inch produces very little improvement. The minimum value for θ_{JA} for the DDPAK/TO-263 package mounted to a PCB is 32°C/W.

Figure 22 shows the maximum allowable power dissipation for DDPAK/TO-263 packages for different ambient temperatures, assuming θ_{1A} is 35°C/W and the maximum junction temperature is 125°C.

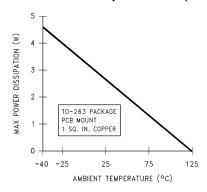


Figure 22. Maximum Power Dissipation vs Ambient Temperature For DDPAK/TO-263 Package



HEATSINKING PSOP PACKAGE

Heatsinking for the SO PowerPad package is accomplished by allowing heat to flow through the ground slug on the bottom of the package into the copper on the PC board. The heat slug must be soldered down to a copper plane to get good heat transfer. It can also be connected through vias to internal copper planes. Since the heat slug is at ground potential, traces must not be routed under it which are not at ground potential. Under all possible conditions, the junction temperature must be within the range specified under operating conditions.

Figure 23 shows a curve for the θ_{JA} of the PSOP package for different copper area sizes using a typical PCB with one ounce copper in still air.

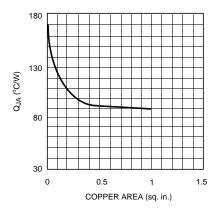


Figure 23. θ_{JA} vs. Copper (1 ounce) Area for PSOP Package

Copyright © 2003–2013, Texas Instruments Incorporated



REVISION HISTORY

Changes from Revision E (April 2013) to Revision F							
•	Changed layout of National Data Sheet to TI format		11				

PACKAGE OPTION ADDENDUM



11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty		Lead/Ball Finish		Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
LP3882EMR-1.2	ACTIVE	SO PowerPAD	DDA	8	95	TBD	Call TI	Call TI	-40 to 125	3882E MR1.2	Samples
LP3882EMR-1.2/NOPB	ACTIVE	SO PowerPAD	DDA	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 125	3882E MR1.2	Samples
LP3882EMR-1.5	ACTIVE	SO PowerPAD	DDA	8	95	TBD	Call TI	Call TI	-40 to 125	3882E MR1.5	Samples
LP3882EMR-1.5/NOPB	ACTIVE	SO PowerPAD	DDA	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 125	3882E MR1.5	Samples
LP3882EMR-1.8	ACTIVE	SO PowerPAD	DDA	8	95	TBD	Call TI	Call TI	-40 to 125	3882E MR1.8	Samples
LP3882EMR-1.8/NOPB	ACTIVE	SO PowerPAD	DDA	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 125	3882E MR1.8	Samples
LP3882EMRX-1.2	ACTIVE	SO PowerPAD	DDA	8	2500	TBD	Call TI	Call TI	-40 to 125	3882E MR1.2	Samples
LP3882EMRX-1.2/NOPB	ACTIVE	SO PowerPAD	DDA	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 125	3882E MR1.2	Samples
LP3882ES-1.2	ACTIVE	DDPAK/ TO-263	KTT	5	45	TBD	Call TI	Call TI	-40 to 125	LP3882ES -1.2	Samples
LP3882ES-1.2/NOPB	ACTIVE	DDPAK/ TO-263	KTT	5	45	Pb-Free (RoHS Exempt)	CU SN	Level-3-245C-168 HR	-40 to 125	LP3882ES -1.2	Samples
LP3882ES-1.5	ACTIVE	DDPAK/ TO-263	KTT	5	45	TBD	Call TI	Call TI	-40 to 125	LP3882ES -1.5	Samples
LP3882ES-1.5/NOPB	ACTIVE	DDPAK/ TO-263	KTT	5	45	Pb-Free (RoHS Exempt)	CU SN	Level-3-245C-168 HR	-40 to 125	LP3882ES -1.5	Samples
LP3882ESX-1.2	ACTIVE	DDPAK/ TO-263	KTT	5	500	TBD	Call TI	Call TI	-40 to 125	LP3882ES -1.2	Samples
LP3882ESX-1.2/NOPB	ACTIVE	DDPAK/ TO-263	KTT	5	500	Pb-Free (RoHS Exempt)	CU SN	Level-3-245C-168 HR	-40 to 125	LP3882ES -1.2	Samples
LP3882ESX-1.5	ACTIVE	DDPAK/ TO-263	KTT	5	500	TBD	Call TI	Call TI	-40 to 125	LP3882ES -1.5	Samples
LP3882ESX-1.5/NOPB	ACTIVE	DDPAK/ TO-263	KTT	5	500	Pb-Free (RoHS Exempt)	CU SN	Level-3-245C-168 HR	-40 to 125	LP3882ES -1.5	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.



PACKAGE OPTION ADDENDUM

11-Apr-2013

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 8-Apr-2013

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

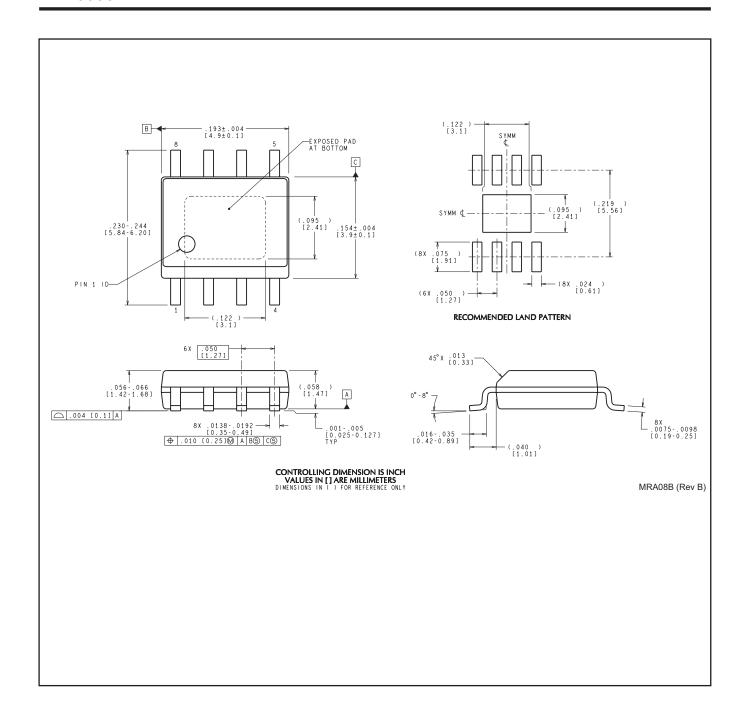
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LP3882EMRX-1.2	SO Power PAD	DDA	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LP3882EMRX-1.2/NOPB	SO Power PAD	DDA	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LP3882ESX-1.2	DDPAK/ TO-263	KTT	5	500	330.0	24.4	10.75	14.85	5.0	16.0	24.0	Q2
LP3882ESX-1.2/NOPB	DDPAK/ TO-263	KTT	5	500	330.0	24.4	10.75	14.85	5.0	16.0	24.0	Q2
LP3882ESX-1.5	DDPAK/ TO-263	KTT	5	500	330.0	24.4	10.75	14.85	5.0	16.0	24.0	Q2
LP3882ESX-1.5/NOPB	DDPAK/ TO-263	KTT	5	500	330.0	24.4	10.75	14.85	5.0	16.0	24.0	Q2

www.ti.com 8-Apr-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LP3882EMRX-1.2	SO PowerPAD	DDA	8	2500	367.0	367.0	35.0
LP3882EMRX-1.2/NOPB	SO PowerPAD	DDA	8	2500	367.0	367.0	35.0
LP3882ESX-1.2	DDPAK/TO-263	KTT	5	500	367.0	367.0	45.0
LP3882ESX-1.2/NOPB	DDPAK/TO-263	KTT	5	500	367.0	367.0	45.0
LP3882ESX-1.5	DDPAK/TO-263	KTT	5	500	367.0	367.0	45.0
LP3882ESX-1.5/NOPB	DDPAK/TO-263	KTT	5	500	367.0	367.0	45.0





IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive Communications and Telecom **Amplifiers** amplifier.ti.com www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps

DSP **Energy and Lighting** dsp.ti.com www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical logic.ti.com Logic Security www.ti.com/security

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

OMAP Applications Processors <u>www.ti.com/omap</u> TI E2E Community <u>e2e.ti.com</u>

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>